

SAM™ Data Sheet SAM-1064-65-10ps-x, $\lambda = 1064 \text{ nm}$

Laser wavelength	$\lambda = 1064 \text{ nm}$
High reflection band	$\lambda = 1010 \dots 1110 \text{ nm}$
Absorbance	$A = 65 \%$
Modulation depth	$\Delta R = 54 \%$
Saturation fluence	$\Phi_{\text{sat}} = 28 \mu\text{J}/\text{cm}^2$
Relaxation time constant	$\tau = 10 \text{ ps}$
Damage threshold	$\Phi = 800 \mu\text{J}/\text{cm}^2$
Chip area	4.0 mm x 4.0 mm; other dimensions on request
Chip thickness	450 μm
Protection	the SAM is protected with a dielectric front layer

Mounting option **x** denotes the type of mounting as follows:

- x = 0** unmounted
- x = 12.7 g** glued on a gold plated Cu-cylinder with 12.7 mm \varnothing
- x = 25.4 g** glued on a gold plated Cu-cylinder with 25.4 mm \varnothing
- x = 12.7 s** soldered on a gold plated Cu-cylinder with 12.7 mm \varnothing
- x = 25.4 s** soldered on a gold plated Cu-cylinder with 25.4 mm \varnothing
- x = FC/PC** mounted on a 1 m monomode fiber cable with FC/PC connector

Low intensity spectral reflectance

